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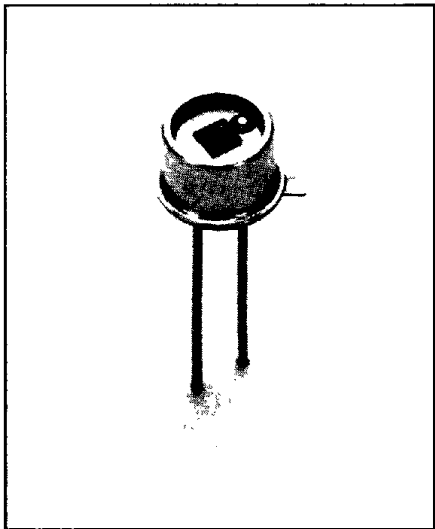
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SIEMENS

T-41-50
SFH202
SFH202a
PIN PHOTODIODE



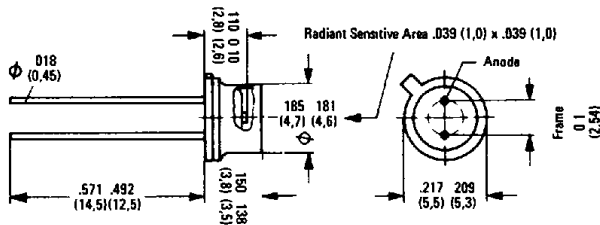
FEATURES

- TO-18 Hermetic Package
- Flat Glass Lens
- For Fiber Optic Communications

DESCRIPTION

SFH202 and SFH202a are planar silicon PIN-photo diodes. The case (18A2 DIN 41876 —similar to TO-18) has a flat glass lens top. The cathode is electrically connected to the case. The diode is a receiver with high operating frequency, very low reverse current, and fast switching time. Because of the flat lens, the diode is especially suitable for use with fiber optic cables, up to 560 Mbits.

Package Dimensions in Inches (mm)



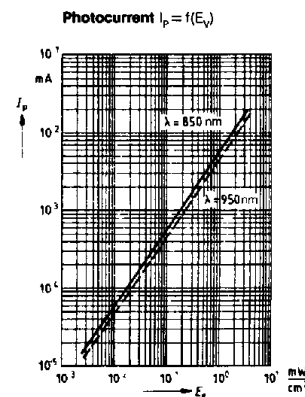
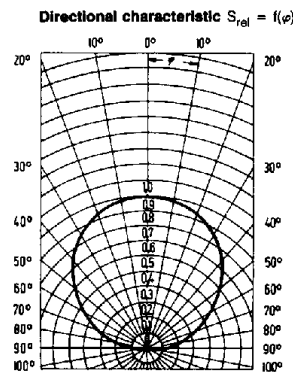
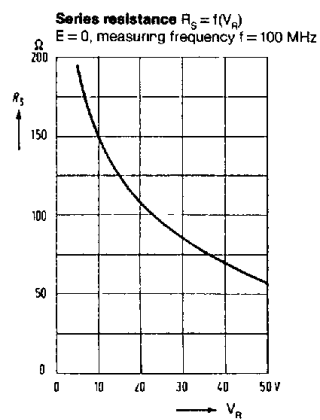
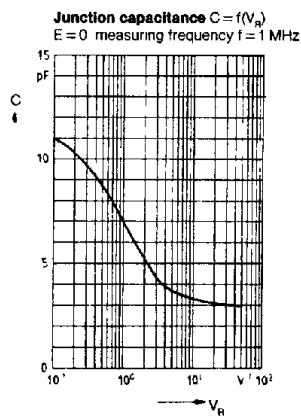
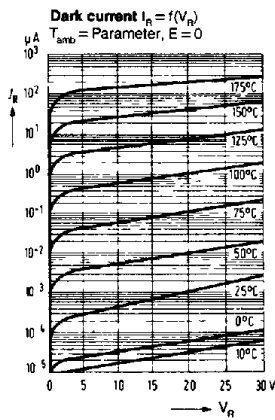
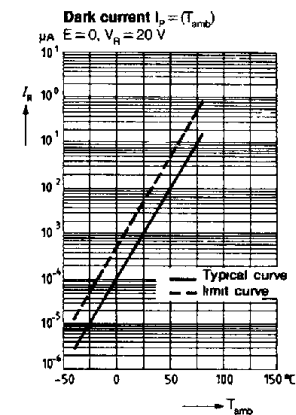
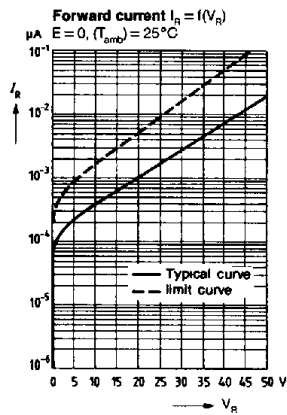
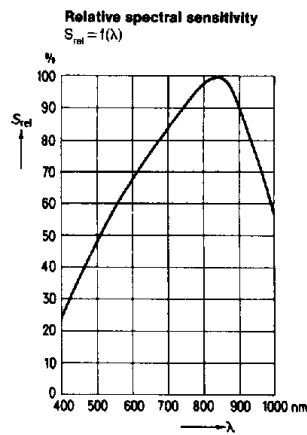
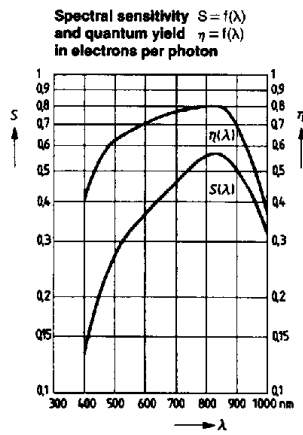
Maximum Ratings

Reverse Voltage (V_R)	50 V
Storage Temperature Range (T_S)	-40 to +80°C
Junction Temperature (T_J)	80°C

Characteristics ($T_{amb} = 25^\circ\text{C}$)

Wavelength of Max. Photosensitivity	λ_{Smax}	850	nm
Radiant Sensitive Area	A	1	mm ²
Dark Current ($V_R = 20\text{ V}$, $E = 0$)	I_R	1 (≤ 5)	nA
Spectral Sensitivity ($\lambda = 850\text{ nm}$)	S_λ	0.55	A/W
($\lambda = 950\text{ nm}$)	S_λ	0.45 (≥ 0.35)	A/W
Quantum Yield (Electrons per photon) ($\lambda = 850\text{ nm}$)	η	0.80	Electrons/Photon
Rise Time of the Photocurrent			
SFH202 ($R_L = 50\Omega$, $V_R = 20\text{ V}$, $\lambda = 900\text{ nm}$)	t_r	0.5 (≤ 1)	ns
SFH202a ($R_L = 50\Omega$, $V_R = 50\text{ V}$, $\lambda = 850\text{ nm}$)	t_r	3	ns
Cut-off Frequency			
($R_L = 50\Omega$, $V_R = 20$)	f_q	500	MHz
SFH202 ($\lambda = 900\text{ nm}$)	f_q	200	MHz
SFH202a ($\lambda = 850\text{ nm}$)			
Capacitance			
($V_R = 0\text{ V}$)	C_0	13	pF
($V_R = 1\text{ V}$)	C_1	7	pF
($V_R = 12\text{ V}$)	C_{12}	33	pF
($V_R = 20\text{ V}$)	C_{20}	3	pF
Temperature Coefficient for I_P	TK	0.2	%/K
Noise Equivalent Power ($V_R = 20\text{ V}$)	NEP	3.3×10^{-14}	$\frac{W}{\sqrt{\text{Hz}}}$
Detection Limit	D^*	3.1×10^{12}	$\frac{\text{cm} \sqrt{\text{Hz}}}{W}$

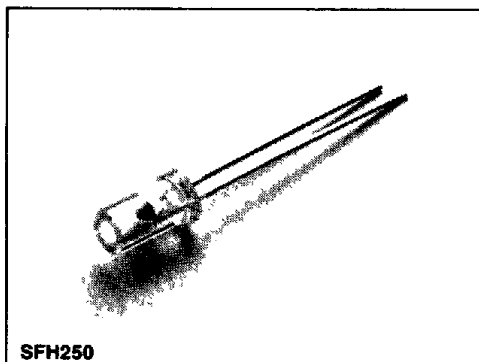
T-4150



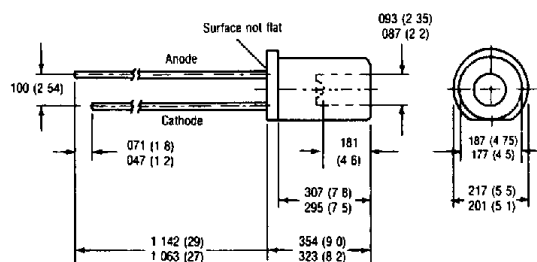
Fiber Optic
Devices

SIEMENS**SFH250**
WITH IR FILTER SFH250F**PLASTIC FIBER OPTIC**
PHOTODIODE DETECTOR

T-41-50

Preliminary Data Sheet

Package Dimensions in Inches (mm)

**FEATURES**

- **2.3 mm Aperture Holds Standard 1000 Micron Plastic Fiber**
- **No Fiber Stripping Required**
- **Daylight Rejection Filter (SFH250F)**
- **High Reliability**
- **Low Noise**
- **Fast Switching Times**
- **Low Capacitance**
- **Very Good Linearity**
- **Sensitive in the Visible (SFH250) and Near IR Range (SFH250 & 250F)**
- **Molded Microlens for Efficient Coupling**

DESCRIPTION

The SFH250/250F are fast silicon PIN photodiodes in a low cost plastic package for use in short distance data transmission using 1000 micron plastic fibers. Both come in a 5 mm (T1 3/4) plastic package featuring a tubular aperture which is wide enough to accommodate fiber and cladding. A microlens on the bottom of the aperture improves the light coupling efficiency of the fiber output into the photodiode.

The SFH250 has a clear plastic housing; the SFH250F has a black plastic housing.

Typical applications include automotive wiring, isolation interconnects, medical instruments, robotics, electronic games, and copy machines.

For application information see Appnote 40

Maximum Ratings

Operating and Storage Temperature Range (T)	-55 to +100°C
Soldering Temperature (Distance from solder to package = 2 mm)	
Dip Soldering Time, t _s ≤ 5 sec (T _s)	260°C
Reverse Voltage (V _R)	30 V
Power Dissipation (P _{TOT})	100 mW
Thermal Resistance (R _{THJA})	750 K/W

Characteristics (T_{amb} = 25°C)

Wavelength of Max. Photosensitivity			
SFH250	λ _{MAX}	850	nm
SFH250F	λ _{MAX}	900	nm
Spectral Range of Photosensitivity (S = 10% of S _{MAX})			
SFH250	λ	400 to 1100	nm
SFH250F	λ	800 to 1100	nm
Dark Current (V _R = 20 V)	I _R	1 (≤10)	nA
Quantum Efficiency (λ = 850 nm)	η	0.89	Electrons/Photon
Rise and Fall Time of the Photocurrent from 10% to 90%, respectively and from 90% to 10% of its Peak Value (R _f = 50Ω, V _R = 30 V, λ = 880 nm)	t _R , t _F	10	ns
Capacitance (V _R = 0 V, f = 1 MHz, E _V = 0 lx)	C ₀	11	pF
Noise Equivalent Power	NEP	2.9 × 10 ⁻¹⁴	W/√Hz
Detection Limit (V _R = 20 V)	D _L	3.5 × 10 ¹²	cm/√Hz
Photocurrent (V _R = 5 V) (Note 1)			
SFH250/250F λ = 950 nm	I _{PH}	4.0	μA
SFH250 λ = 660 nm	I _{PH}	3.0	μA

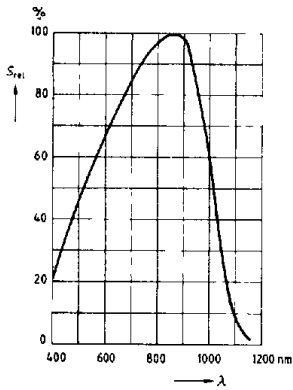
¹ Photocurrent generated at 10 μW light incidence through plastic 1000 micron fiber (distance lens fiber ≤ 0.1 mm; fiber type ESKA EH4001; fiber face polished)

T-41-50

SFH250

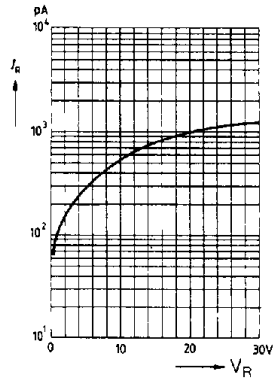
Relative spectral sensitivity

$$S_{rel} = f(\lambda)$$



Dark current $I_R = f(V_R)$

$$T_{amb} = 25^\circ\text{C}$$



Capacitance $C = f(V_R)$

$$T_{amb} = 25^\circ\text{C}$$

